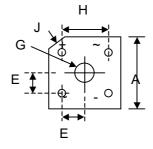
# **SEMICONDUCTOR**

### 8.0A GLASS PASSIVATED BRIDGE RECTIFIER

# Data Sheet 1348 Rev.—

### **Features**

- Glass Passivated Die Construction
- High Current Capability
- High Case Dielectric Strength
- High Surge Current Capability
- Ideal for Printed Circuit Board Application
- Plastic Material has Underwriters Laboratory Flammability Classification 94V-O



#### Dim Min Max 18.54 19.56 Α В 6.35 7.60 С 19.00 D 1.27 Ø Typical Ε 5.33 7.37 Hole for #6 screw G 3.60 4.00 Н 12.20 13.20 J 2.38 x 45°C Typical All Dimensions in mm

KBPC-8

### **Mechanical Data**

Case: Molded Plastic

 Terminals: Plated Leads Solderable per MIL-STD-202, Method 208

Polarity: Marked on Body

Weight: 5.4 grams (approx.)

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Mounting Position: Through Hole for #6 Screw

Mounting Torque: 5.0 Inch-pounds Maximum

Marking: Type Number

## Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	KBPC 800G	KPBC 801G	KBPC 802G	KBPC 804G	KBPC 806G	KBPC 808G	KBPC 810G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		VRRM VRWM VR	50	100	200	400	600	800	1000	>
RMS Reverse Voltage		VR(RMS)	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T <sub>A</sub> = 50°C		lo	8.0							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	160							А
Forward Voltage (per element) @I <sub>F</sub> = 4	I.0A	VFM				1.1				V
Peak Reverse Current $@T_C = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_C = 125^{\circ}C$		lR	5.0 500						μΑ	
I <sup>2</sup> t Rating for Fusing (t<8.3ms) (Note 2)		l <sup>2</sup> t	160						A <sup>2</sup> s	
Typical Junction Capacitance (Note 3)		Cj	200					pF		
Typical Thermal Resistance (Note 4)		$R_{\theta}$ JC	6.0					K/W		
Operating and Storage Temperature Range		Tj, Tstg	-55 to +150						°C	

Note: 1. Mounted on 8.6" sq. x 0.24" thick Al. plate.

- 2. Non-repetitive, for t > 1ms and < 8.3ms.
- 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 4. Thermal resistance junction to case per element.

